

描述 / Descriptions

TO-252 塑封封装 N 沟道 MOS 场效应管。N-CHANNEL MOSFET in a TO-252 Plastic Package.

特征 / Features

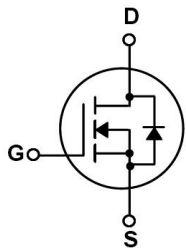
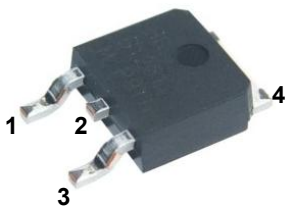
$R_{DS(on)}$ 小, 门电荷低, C_{rss} 小, 开关速度快。

Low $R_{DS(on)}$, low gate charge, low C_{rss} , fast switching.

用途 / Applications

用于低压电路如: 汽车电路、DC/DC 转换、便携式产品的电源高效转换。

Suited for low voltage applications such as automotive, DC/DC Converters, and high efficiency switching for power management in portable and battery operated products.

内部等效电路 / Equivalent Circuit**引脚排列 / Pinning**

PIN1 : G

PIN 2 : D

PIN 3 : S

PIN 4 : D

放大及印章代码 / h_{FE} Classifications & Marking

见印章说明。See Marking Instructions.

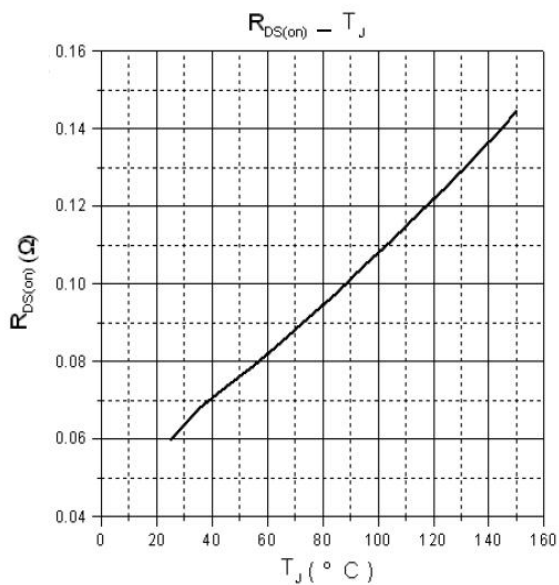
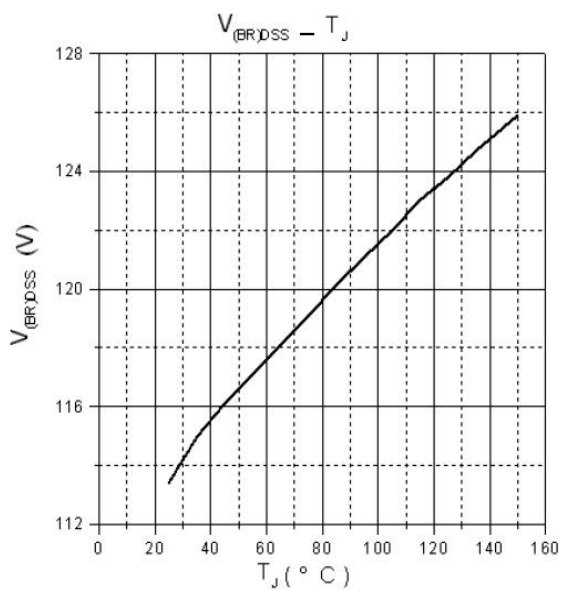
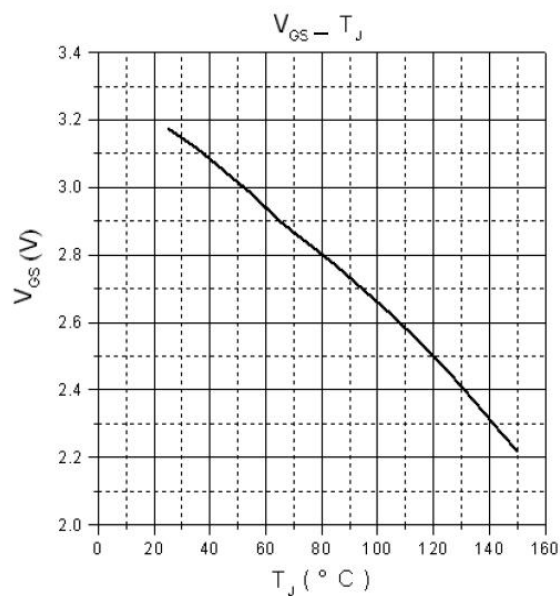
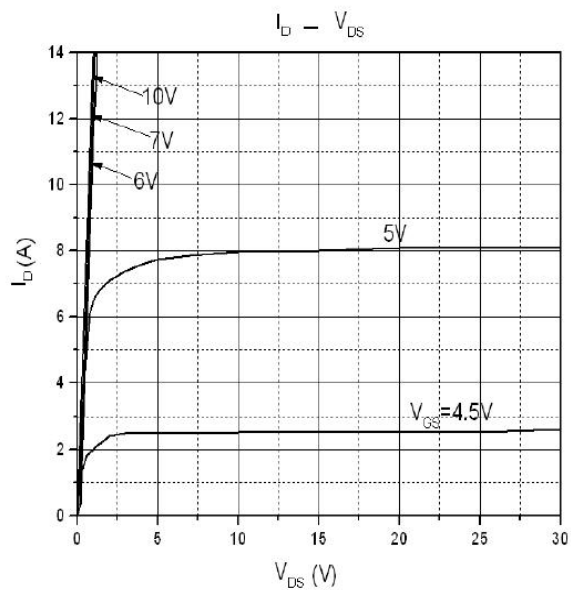

极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	V_{DS}	100	V
Drain Current	$I_D(T_c=25^{\circ}\text{C})$	15	A
Drain Current	$I_D(T_c=100^{\circ}\text{C})$	10	A
Drain Current - Pulsed	I_{DM}	60	A
Gate-Source Voltage	V_{GS}	± 20	V
Single Pulsed Avalanche Energy	E_{AS}	142	mJ
Avalanche Current	I_{AS}	3.6	A
Power Dissipation	$P_D(T_c=25^{\circ}\text{C})$	39	W
Operating and Storage Temperature Range	$T_j \quad T_{stg}$	-55~175	$^{\circ}\text{C}$

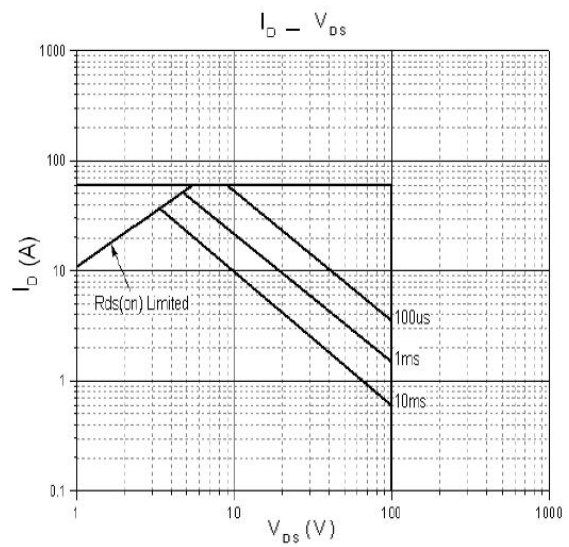
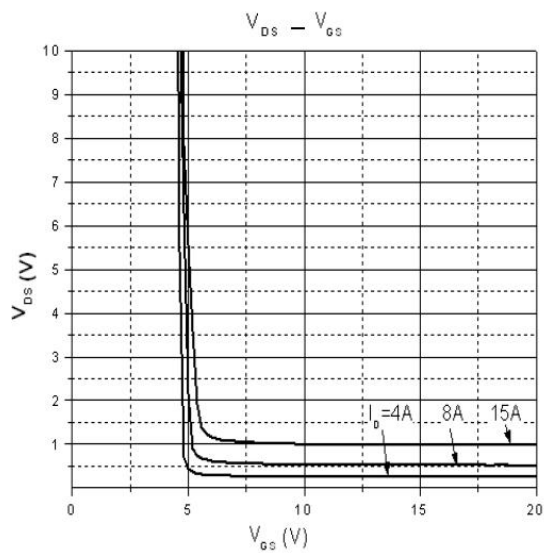
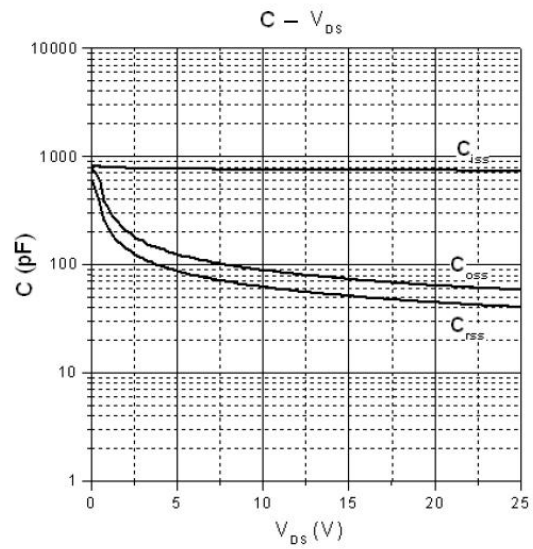
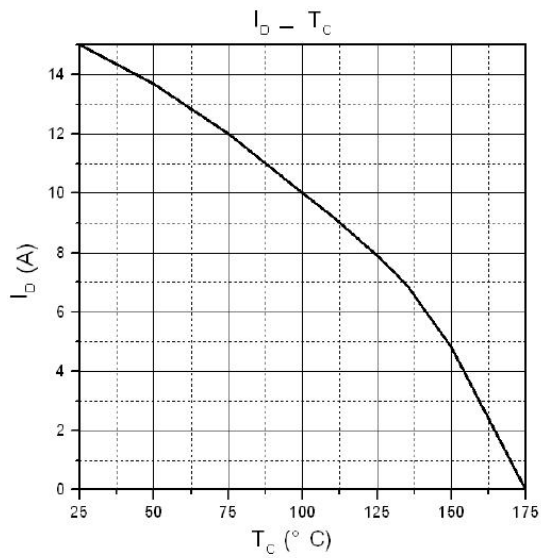
电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V \quad I_D=250\mu A$	100			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V \quad V_{GS}=0V$			1.0	μA
		$T_J=125^{\circ}\text{C}$			50	
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V \quad V_{DS}=0V$			± 100	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS} \quad I_D=250\mu A$	2		4	V
		$T_J=125^{\circ}\text{C}$		2.46		
Total gate charge	Q_g	$V_{DS}=80V \quad I_D=9.2A$ $V_{GS}=10V$		20		nC
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V \quad I_D=2A$		60	90	m Ω
		$T_J=125^{\circ}\text{C}$		125		
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V \quad I_S=50A$			1.5	V
Input Capacitance	C_{iss}	$V_{DS}=25V \quad V_{GS}=0V$ $f=1.0\text{MHz}$		739		pF
Output Capacitance	C_{oss}			58		pF
Reverse Transfer Capacitance	C_{rss}			40		pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=50V \quad I_D=9.2A$ $R_L=5.4\Omega$ $V_{GS}=10V \quad R_{GEN}=18\Omega$		11		ns
Turn-On Rise Time	t_r			31		ns
Turn-Off Delay Time	$t_{d(off)}$			39		ns
Turn-Off Fall Time	t_f			28		ns

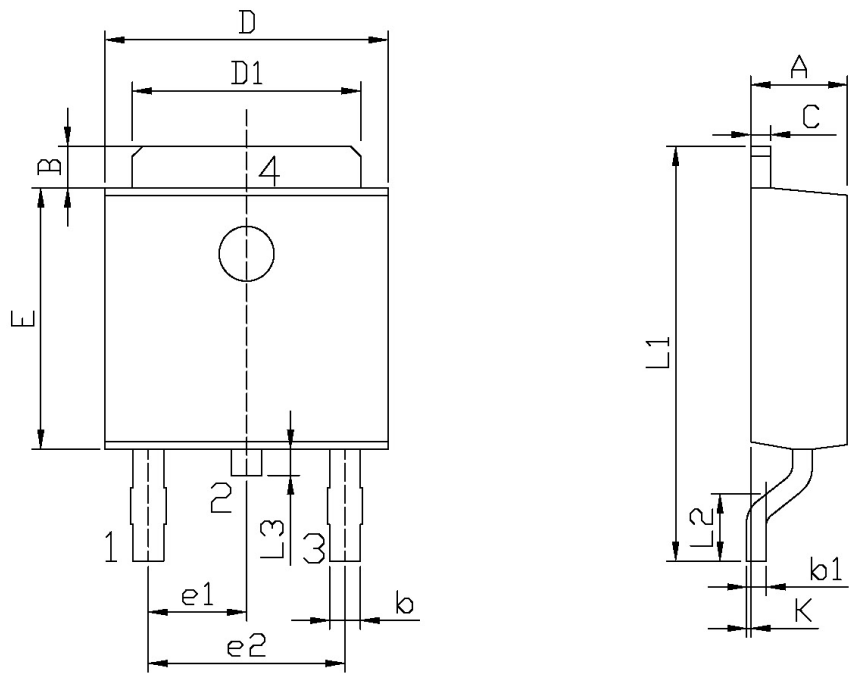
电参数曲线图 / Electrical Characteristic Curve



电参数曲线图 / Electrical Characteristic Curve



外形尺寸图 / Package Dimensions

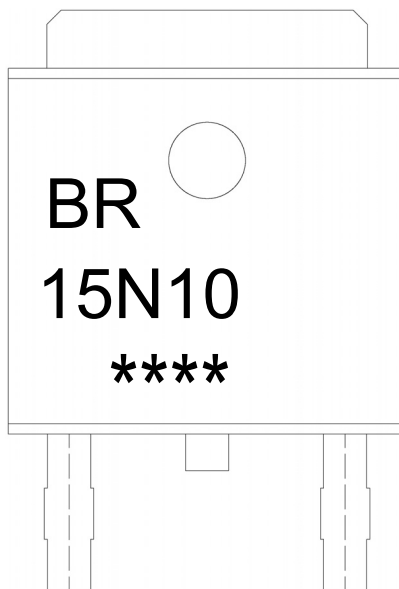


单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	2.20	2.40	E	5.95	6.25
B	0.95	1.25	e1	2.24	2.34
b	0.50	0.70	e2	4.43	4.73
b1	0.45	0.55	L1	9.45	9.95
C	0.45	0.55	L2	1.25	1.75
D	6.45	6.75	L3	0.60	0.90
D1	5.10	5.50	K	0.00	0.10

TO-252

印章说明 / Marking Instructions



说明：

BR： 为公司代码

15N10： 为型号代码

****： 为生产批号代码，随生产批号变化。

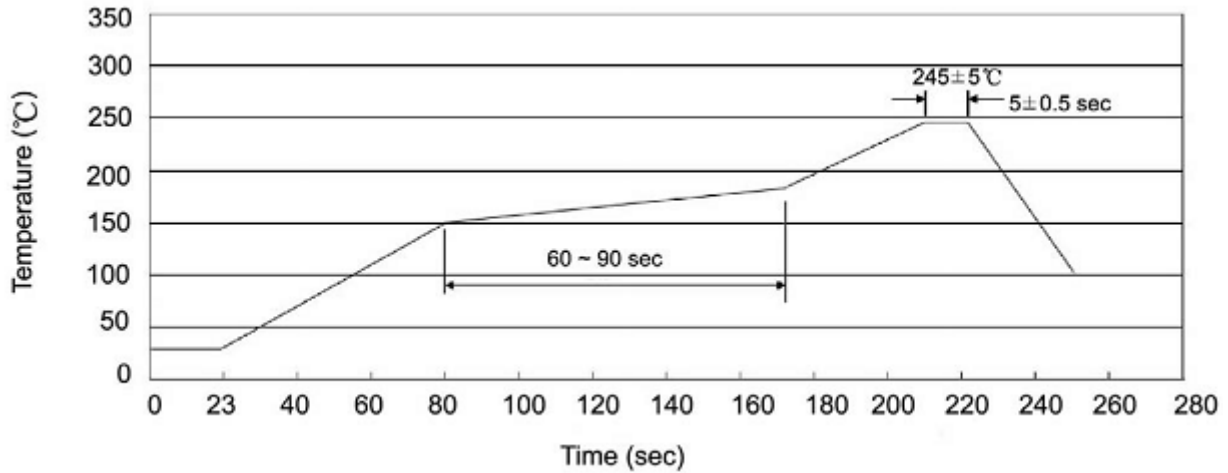
Note:

BR: Company Code

15N10: Product Type.

****: Lot No. Code, code change with Lot No.

回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)



说明：

- 1、预热温度 25~150°C，时间 60~90sec;
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2~10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
TO-252	2,500	2	5,000	5	25,000	13" ×16	360×360×50	385×257×392

套管包装 / TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-251/252	75	48	3,600	5	18,000	526×20.5×5.25	555×164×50	575×290×180

使用说明 / Notices